NSN 5961-00-134-9938

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View Online at https://aerobasegroup.com/nsn/5961-00-134-9938 **Inclosure Material:** Metal **Overall Length:** 0.425 inches **Overall Diameter:** 0.800 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 40.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 2.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: